

LTC2152-14/ LTC2151-14/LTC2150-14

14-Bit 250Msps/ 210Msps/170Msps ADCs

FEATURES

- 70dB SNR
- 90dB SFDR
- Low Power: 356mW/338mW/313mW Total
- Single 1.8V Supply
- DDR LVDS Outputs
- Easy-to-Drive 1.5V_{P-P} Input Range
- 1.25GHz Full Power Bandwidth S/H
- Optional Clock Duty Cycle Stabilizer
- Low Power Sleep and Nap Modes
- Serial SPI Port for Configuration
- Pin Compatible 12-Bit Versions
- 40-Pin (6mm × 6mm) QFN Package

APPLICATIONS

- Communications
- Cellular Basestations
- Software Defined Radios
- Medical Imaging
- High Definition Video
- Testing and Measurement Instruments

DESCRIPTION

The LTC®2152-14/LTC2151-14/LTC2150-14 are 250Msps/210Msps/170Msps 14-bit A/D converters designed for digitizing high frequency, wide dynamic range signals. They are perfect for demanding communications applications with AC performance that includes 70dB SNR and 90dB spurious free dynamic range (SFDR). The 1.25GHz input bandwidth allows the ADC to undersample high frequencies with good performance. The latency is only six clock cycles.

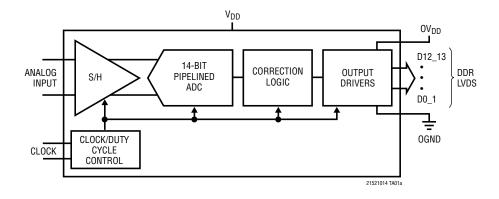
DC specs include ± 0.85 LSB INL (typ), ± 0.25 LSB DNL (typ) and no missing codes over temperature. The transition noise is 1.82LSB_{RMS}.

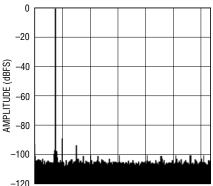
The digital outputs are double-data rate (DDR) LVDS.

The ENC⁺ and ENC⁻ inputs can be driven differentially with a sine wave, PECL, LVDS, TTL, or CMOS inputs. An optional clock duty cycle stabilizer allows high performance at full speed for a wide range of clock duty cycles.

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TYPICAL APPLICATION





60

FREQUENCY (MHz)

80

LTC2152-14: 32K Point FFT, f_{IN} = 15MHz, -1dBFS, 250Msps

21521014 TA01b

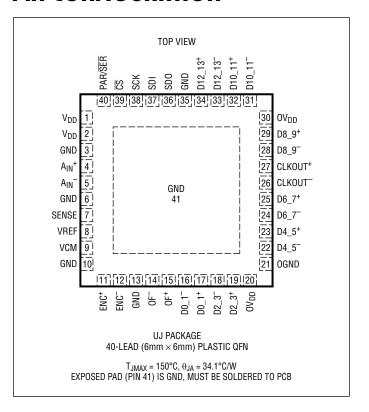
120

100



ABSOLUTE MAXIMUM RATINGS

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC2152CUJ-14#PBF	LTC2152CUJ-14#TRPBF	LTC2152UJ-14	40-Lead (6mm × 6mm) Plastic QFN	0°C to 70°C
LTC2152IUJ-14#PBF	LTC2152IUJ-14#TRPBF	LTC2152UJ-14	40-Lead (6mm × 6mm) Plastic QFN	-40°C to 85°C
LTC2151CUJ-14#PBF	LTC2151CUJ-14#TRPBF	LTC2151UJ-14	40-Lead (6mm × 6mm) Plastic QFN	0°C to 70°C
LTC2151IUJ-14#PBF	LTC2151IUJ-14#TRPBF	LTC2151UJ-14	40-Lead (6mm × 6mm) Plastic QFN	-40°C to 85°C
LTC2150CUJ-14#PBF	LTC2150CUJ-14#TRPBF	LTC2150UJ-14	40-Lead (6mm × 6mm) Plastic QFN	0°C to 70°C
LTC2150IUJ-14#PBF	LTC2150IUJ-14#TRPBF	LTC2150UJ-14	40-Lead (6mm × 6mm) Plastic QFN	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/ For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/



CONVERTER CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25 \, ^{\circ}\text{C}$. (Note 5)

			LTC2152-14		L	TC2151-1	14	LTC2150-14				
PARAMETER	CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Resolution (No Missing Codes)		•	14			14			14			Bits
Integral Linearity Error	Differential Analog Input (Note 6)	•	-5.5	±0.85	5.5	-5.1	±1	5.1	-5.1	±1	5.1	LSB
Differential Linearity Error	Differential Analog Input	•	-0.9	±0.25	0.9	-0.9	±0.25	0.9	-0.9	±0.25	0.9	LSB
Offset Error	(Note 7)	•	-13	±5	13	-13	±5	13	-13	±3	13	mV
Gain Error	External Reference	•	-4	±1	3	-4	±1	3	-4	±1	3	%FS
Offset Drift				±20			±20			±20		μV/°C
Full-Scale Drift	Internal Reference External Reference			±30 ±10			±30 ±10			±30 ±10		ppm/°C ppm/°C
Transition Noise	External Reference			1.82			1.82			1.82		LSB _{RMS}

ANALOG INPUT The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V_{IN}	Analog Input Range (A _{IN} ⁺ – A _{IN} ⁻)	1.7V < V _{DD} < 1.9V	•		1.5		V _{P-P}
V _{IN(CM)}	Analog Input Common Mode $(A_{IN}^+ + A_{IN}^-)/2$	Differential Analog Input (Note 8)	•	V _{CM} – 20mV	V_{CM}	V _{CM} + 20mV	V
V _{SENSE}	External Reference Mode	External Reference Mode	•	1.200	1.250	1.300	V
I _{IN1}	Analog Input Leakage Current	0 < A _{IN} ⁺ , A _{IN} ⁻ < V _{DD} No Encode	•	-1		1	μA
I _{IN2}	SENSE Input Leakage Current	1.2V < SENSE < 1.3V	•	-1		1	μA
I _{IN3}	PAR/SER Input Leakage Current	0 < PAR/SER < V _{DD}	•	-1		1	μA
t _{AP}	Sample-and-Hold Acquisition Delay Time				1		ns
t _{JITTER}	Sample-and-Hold Acquisition Delay Jitter				0.15		ps _{RMS}
CMRR	Analog Input Common Mode Rejection Ratio				75		dB
BW-3B	Full-Power Bandwidth				1250		MHz

DYNAMIC ACCURACY The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $A_{IN} = -1 dBFS$. (Note 5)

				L.	ГС2152-	14	Li	ГС2151-	14	LTC2150-14			
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
SNR	Signal-to-Noise Ratio	15MHz Input 70MHz Input 140MHz Input	•	67.3	70 69.7 69.3		67.4	70 69.8 69.4		67.5	70 69.8 69.5		dBFS dBFS dBFS
SFDR	Spurious Free Dynamic Range 2nd or 3rd Harmonic	15MHz Input 70MHz Input 140MHz Input	•	72	90 85 82		75	90 85 82		76	90 85 83		dBFS dBFS dBFS
	Spurious Free Dynamic Range 4th Harmonic or Higher	15MHz Input 70MHz Input 140MHz Input	•	81	95 95 85		82	95 95 88		83	98 95 88		dBFS dBFS dBFS
S/(N+D)	Signal-to-Noise Plus Distortion Ratio	15MHz Input 70MHz Input 140MHz Input	•	66.7	69.9 69.4 68.8		66.8	69.9 69.4 68.8		66.9	69.9 69.4 68.8		dBFS dBFS dBFS
Cross Talk	Cross-Talk Between Channels	Up to 315MHz Input			-95			-95			-95		dB



INTERNAL REFERENCE CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V _{CM} Output Voltage	I _{OUT} = 0	0.439 • V _{DD} − 18mV	0.439 • V _{DD}	0.439 • V _{DD} + 18mV	V
V _{CM} Output Temperature Drift			±37		ppm/°C
V _{CM} Output Resistance	-1mA < I _{OUT} < 1mA		4		Ω
V _{REF} Output Voltage	I _{OUT} = 0	1.225	1.250	1.275	V
V _{REF} Output Temperature Drift			±30		ppm/°C
V _{REF} Output Resistance	-400μA < I _{OUT} < 1mA		7		Ω
V _{REF} Line Regulation	1.7V < V _{DD} < 1.9V		0.6		mV/V

POWER REQUIREMENTS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

					C2152-	14	L1	C2151-	14	LTC2150-14			
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V_{DD}	Analog Supply Voltage	(Note 9)	•	1.7	1.8	1.9	1.7	1.8	1.9	1.7	1.8	1.9	V
OV _{DD}	Output Supply Voltage	LVDS Mode (Note 9)	•	1.7	1.8	1.9	1.7	1.8	1.9	1.7	1.8	1.9	V
I_{VDD}	Analog Supply Current		•		169	186		160	176		147	162	mA
I _{OVDD}	Digital Supply Current	1.75mA LVDS Mode 3.5mA LVDS Mode	•		29 49	34.5 54.5		28 48	33.5 54		27 47	32.5 52	mA mA
P _{DISS}	Power Dissipation	1.75mA LVDS Mode 3.5mA LVDS Mode	•		356 392	397 433		338 374	377 414		313 349	350 385	mW mW
P _{SLEEP}	Nap Mode Power	Clocked at f _{S(MAX)}			105			98			93		mW
P _{NAP}	Sleep Mode Power	Clocked at f _{S(MAX)}			<2			<2			<2		mW

DIGITAL INPUTS AND OUTPUTS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
ENCODE I	NPUTS (ENC+, ENC ⁻)						
$\overline{V_{\text{ID}}}$	Differential Input Voltage	(Note 8)	•	0.2	1	1.9	V
V _{ICM}	Common Mode Input Voltage	Internally Set Externally Set (Note 8)	•	1.1	1.2	1.5	V
V _{IN}	Input Voltage Range	ENC+, ENC ⁻ to GND	•	0.2		1.9	V
R _{IN}	Input Resistance	(See Figure 2)			10		kΩ
C _{IN}	Input Capacitance	(Note 8)			2		pF
DIGITAL II	NPUTS (CS, SDI, SCK)						
V _{IH}	High Level Input Voltage	V _{DD} = 1.8V	•	1.3			V
V_{IL}	Low Level Input Voltage	V _{DD} = 1.8V	•			0.6	V
I _{IN}	Input Current	V _{IN} = 0V to 1.8V	•	-10		10	μА
C _{IN}	Input Capacitance	(Note 8)			3		pF
SDO OUTI	PUT (Open-Drain Output. Requires 2k Pull	-Up Resistor if SDO Is Used)					
R _{OL}	Logic Low Output Resistance to GND	V _{DD} = 1.8V, SD0 = 0V			200		Ω
I _{OH}	Logic High Output Leakage Current	SDO = 0V to 3.6V	•	-10		10	μА
C _{OUT}	Output Capacitance	(Note 8)			4		pF



DIGITAL INPUTS AND OUTPUTS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
DIGITAL	DATA OUTPUTS						
V_{OD}	Differential Output Voltage	100Ω Differential Load, 3.5mA Mode 100Ω Differential Load, 1.75mA Mode	•	247 125	350 175	454 250	mV mV
V _{OS}	Common Mode Output Voltage	100Ω Differential Load, 3.5mA Mode 100Ω Differential Load, 1.75mA Mode	•	1.125 1.125	1.250 1.250	1.375 1.375	V
R _{TERM}	On-Chip Termination Resistance	Termination Enabled, OV _{DD} = 1.8V			100		Ω

TIMING CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

				LTC2152-14		LTC2151-14			LTC2150-14				
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
$\overline{f_S}$	Sampling Frequency	(Note 9)	•	10		250	10		210	10		170	MHz
tL	ENC Low Time (Note 8)	Duty Cycle Stabilizer Off Duty Cycle Stabilizer On	•	1.9 1.5	2 2	50 50	2.26 1.5	2.38 2.38	50 50	2.79 1.5	2.94 2.94	50 50	ns ns
t _H	ENC High Time (Note 8)	Duty Cycle Stabilizer Off Duty Cycle Stabilizer On	•	1.9 1.5	2 2	50 50	2.26 1.5	2.38 2.38	50 50	2.79 1.5	2.94 2.94	50 50	ns ns

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
DIGITAL D	DATA OUTPUTS						
$\overline{t_{D}}$	ENC to Data Delay	C _L = 5pF (Note 8)	•	1.7	2	2.3	ns
$\overline{t_{\text{C}}}$	ENC to CLKOUT Delay	C _L = 5pF (Note 8)	•	1.3	1.6	2	ns
t _{SKEW}	DATA to CLKOUT Skew	t _D - t _C (Note 8)	•	0.3	0.4	0.55	ns
	Pipeline Latency			6		6	Cycles
SPI Port T	Fiming (Note 8)		1	l .	,		-
t _{SCK}	SCK Period	Write Mode, C _{SDO} = 20pF Readback Mode R _{PULLUP} = 2k, C _{SDO} = 20pF		40 250			ns ns
$\overline{t_S}$	CS to SCK Set-Up Time		•	5			ns
t _H	SCK to CS Hold Time		•	5			ns
$\overline{t_{DS}}$	SDI Set-Up Time		•	5			ns
t_{DH}	SDI Hold Time		•	5			ns
$\overline{t_{DO}}$	SCK Falling to SDO Valid	Readback Mode R _{PULLUP} = 2k, C _{SDO} = 20pF	•		,	125	ns

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: All voltage values are with respect to GND with GND and OGND shorted (unless otherwise noted).

Note 3: When these pin voltages are taken below GND or above V_{DD} , they will be clamped by internal diodes. This product can handle input currents of greater than 100mA below GND or above V_{DD} without latchup.

Note 4: When these pin voltages are taken below GND they will be clamped by internal diodes. When these pin voltages are taken above V_{DD} they will not be clamped by internal diodes. This product can handle input currents of greater than 100mA below GND without latchup.

Note 5: $V_{DD} = 0V_{DD} = 1.8V$, $f_{SAMPLE} = 250MHz$ (LTC2152), 210MHz (LTC2151), or 170MHz (LTC2150), LVDS outputs, differential ENC+/ENC⁻ = $2V_{P-P}$ sine wave, input range = $1.5V_{P-P}$ with differential drive, unless otherwise noted.

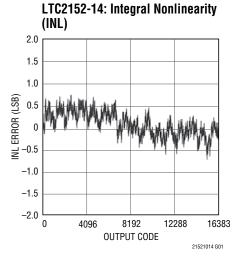
Note 6: Integral nonlinearity is defined as the deviation of a code from a best fit straight line to the transfer curve. The deviation is measured from the center of the quantization band.

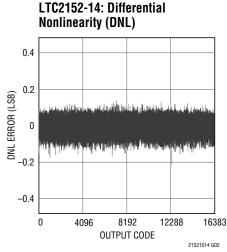
Note 7: Offset error is the offset voltage measured from -0.5LSB when the output code flickers between 00 0000 0000 0000 and 11 1111 1111 in 2's complement output mode.

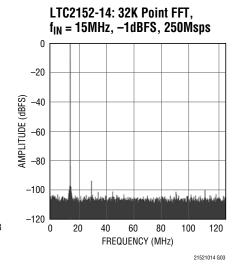
Note 8: Guaranteed by design, not subject to test.

Note 9: Recommended operating conditions.

TECHNOLOGY TECHNOLOGY

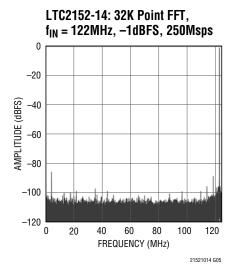


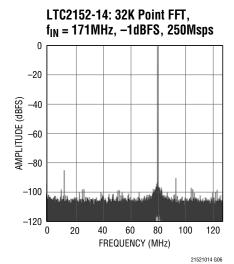


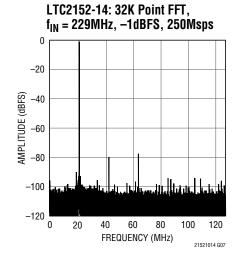


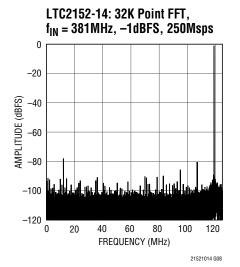
LTC2152-14: 32K Point FFT, f_{IN} = 70MHz, -1dBFS, 250Msps

0
-20
-20
-20
-100
-120
0
20
40
60
80
100
120
FREQUENCY (MHz)









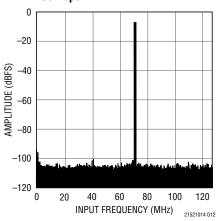


LTC2152-14: 32K Point FFT, $f_{IN} =$ 421MHz, -1dBFS, 250MHz 0 -20 AMPLITUDE (dBFS) -40 -60 -80 -120 20 40 60 80 100 INPUT FREQUENCY (MHz) 21521014 G09

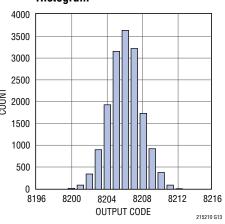
LTC2152-14: 32K Point FFT, $f_{IN} =$ 571MHz, -1dBFS, 250MHz -20 AMPLITUDE (dBFS) -40 -60 -80 -120 0 20 40 60 80 100 INPUT FREQUENCY (MHz) 21521014 G10

LTC2152-14: 32K Point FFT, $f_{IN} =$ 907MHz, -1dBFS, 250Msps -20 AMPLITUDE (dBFS) -40 -60 -80 -100 -120 20 60 80 40 100 0 INPUT FREQUENCY (MHz) 21521014 G11

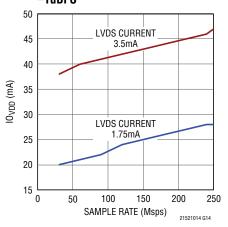
LTC2152-14: 32K Point 2-Tone FFT, f_{IN} = 70.5MHz and 69.5MHz, 250Msps



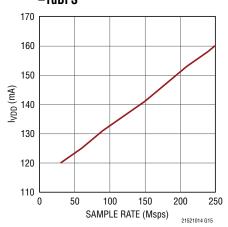
LTC2152-14: Shorted Input Histogram



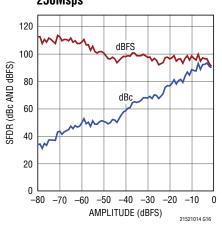
LTC2152-14: I_{OVDD} vs Sample Rate, 15MHz Sine Wave Input, -1dBFS



LTC2152-14: I_{VDD} vs Sample Rate, 15MHz Sine Wave Input, -1dBFS

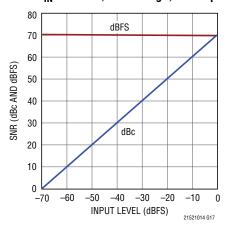


LTC2152-14: SFDR vs Input Level, f_{IN} = 70MHz, 1.5V Range, 250Msps

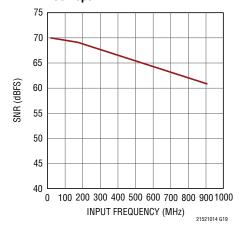




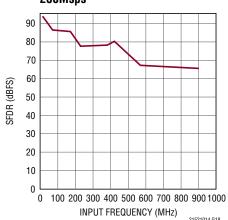
LTC2152-14: SNR vs Input Level, f_{IN} = 70MHz, 1.5V Range, 250Msps



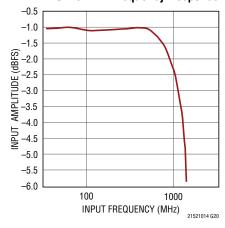
LTC2152-14: SNR vs Input Frequency, -1dBFS, 1.5V Range, 250Msps



LTC2152-14: SFDR vs Input Frequency, -1dBFS, 1.5V Range, 250Msps



LTC2152-14: Frequency Response



LTC2151-14: Integral Nonlinearity INL

2.0

1.5

1.0

(RS)
0.5

-1.0

-1.5

-2.0

8192

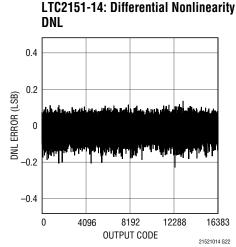
OUTPUT CODE

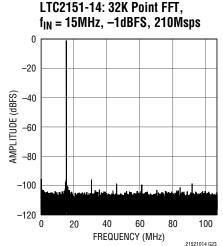
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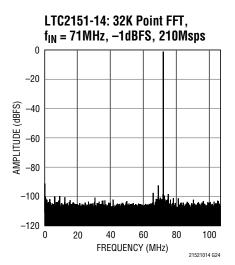
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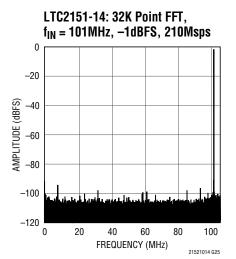
21521014 G21

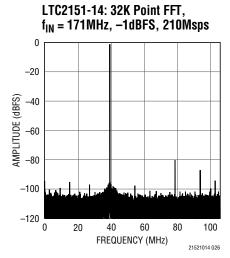
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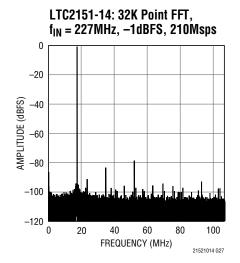


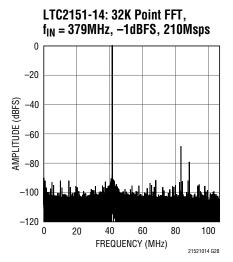


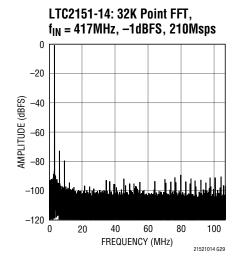


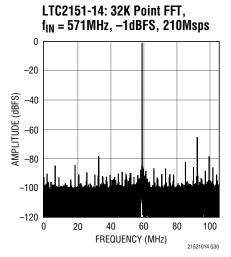


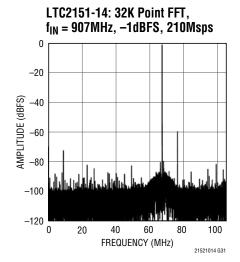




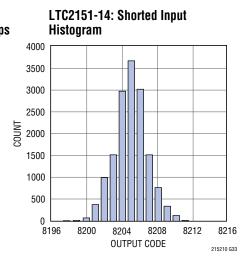


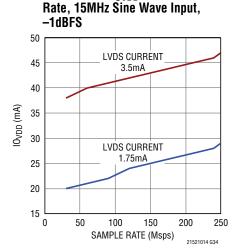




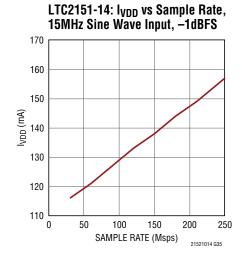


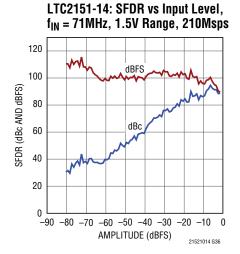
LTC2151-14: 32K Point 2-Tone FFT, $f_{IN} = 70.5MHz$ and 69.5MHz, 210Msps0 -20 AMPLITUDE (dBFS) -40 -60 -80 -100-120 20 40 60 80 100 FREQUENCY (MHz)





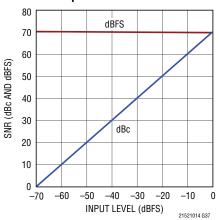
LTC2151-14: I_{OVDD} vs Sample



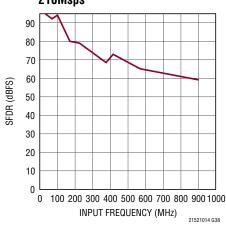




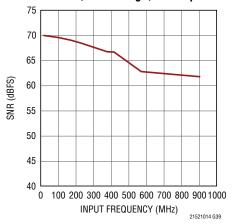
LTC2151-14: SNR vs Input Level, f_{IN} = 71MHz, 1.5V Range, 210Msps



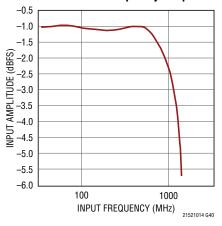
LTC2151-14: SFDR vs Input Frequency, -1dBFS, 1.5V Range, 210Msps

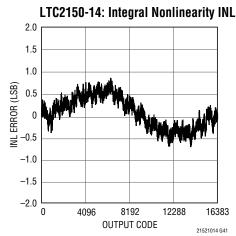


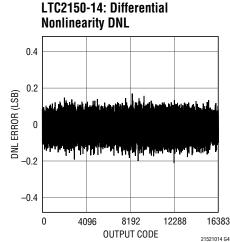
LTC2151-14: SNR vs Input Frequency, -1dBFS, 1.5V Range, 210Msps

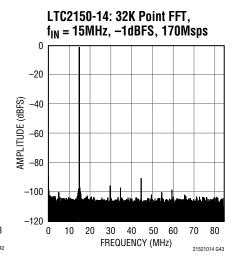


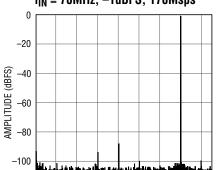
LTC2151-14: Frequency Response



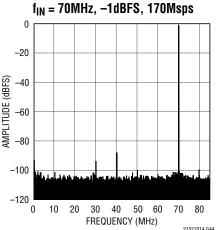


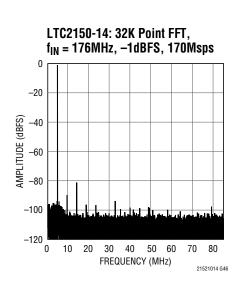


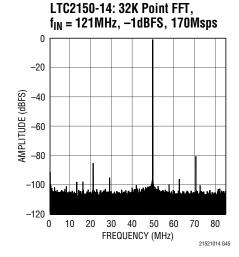


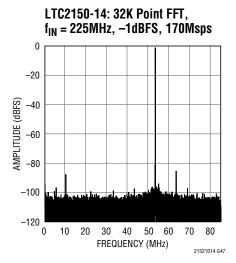


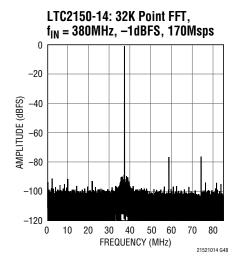
LTC2150-14: 32K Point FFT,

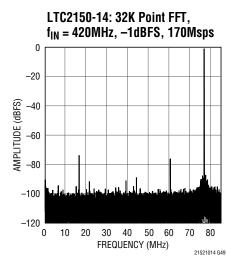


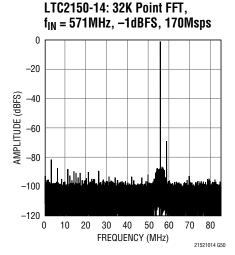


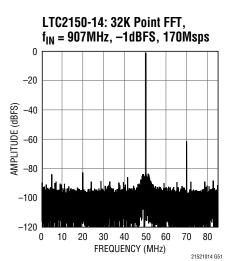


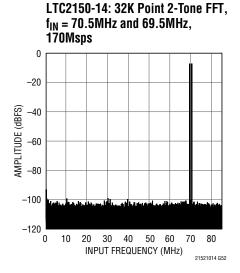


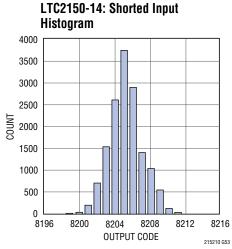




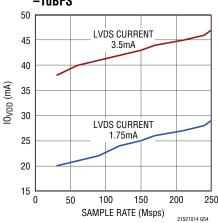








LTC2150-14: I_{OVDD} vs Sample Rate, 15MHz Sine Wave Input, -1dBFS



15MHz Sine Wave Input, -1dBFS

160

150

140

120

110

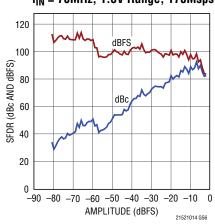
0 50 100 150 200 250

SAMPLE RATE (Msps)

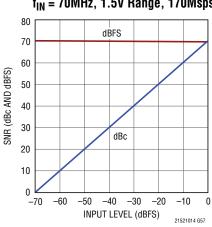
21521014 G55

LTC2150-14: IVDD vs Sample Rate,

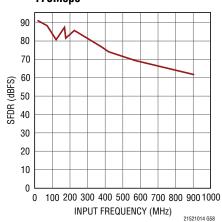
LTC2150-14: SFDR vs Input Level, f_{IN} = 70MHz, 1.5V Range, 170Msps



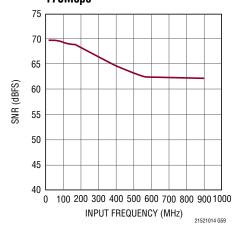
LTC2150-14: SNR vs Input Level, f_{IN} = 70MHz, 1.5V Range, 170Msps



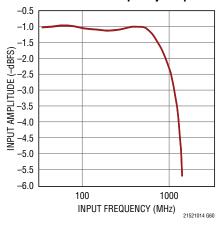
LTC2150-14: SFDR vs Input Frequency, -1dBFS, 1.5V Range, 170Msps



LTC2150-14: SNR vs Input Frequency, -1dBFS, 1.5V Range, 170Msps



LTC2150-14: Frequency Response



PIN FUNCTIONS

 V_{DD} (Pins 1, 2): 1.8V Analog Power Supply. Bypass to ground with 0.1µF ceramic capacitor. Pins 1, 2 can share a bypass capacitor.

GND (Pins 3, 6, 10, 13, 35, Exposed Pad Pin 41): ADC Power Ground. The exposed pad must be soldered to the PCB ground.

A_{IN}+ (Pin 4): Positive Differential Analog Input.

A_{IN}⁻ (**Pin 5**): Negative Differential Analog Input.

SENSE (Pin 7): Reference Programming Pin. Connecting SENSE to V_{DD} selects the internal reference and a $\pm 0.75V$ input range. An external reference between 1.2V and 1.3V applied to SENSE selects an input range of $\pm 0.6 \times V_{SENSE}$.

V_{REF} (**Pin 8**): Reference Voltage Output. Bypass to ground with a 2.2µF ceramic capacitor. Nominally 1.25V.

 V_{CM} (Pin 9): Common Mode Bias Output; nominally equal to 0.439 • V_{DD} . V_{CM} should be used to bias the common mode of the analog inputs. Bypass to ground with a 0.1µF ceramic capacitor.

ENC+ (Pin 11): Encode Input. Conversion starts on the rising edge.

ENC⁻ (**Pin 12**): Encode Complement Input. Conversion starts on the falling edge.

 OV_{DD} (Pins 20, 30): 1.8V Output Driver Supply. Bypass to ground with a $0.1\mu F$ ceramic capacitor.

OGND (Pin 21): LVDS Driver Ground.

SDO (Pin 36): Serial Interface Data Output. In serial programming mode, (PAR/SER = 0V), SDO is the optional serial interface data output. Data on SDO is read back from the

mode control registers and can be latched on the falling edge of SCK. SDO is an open-drain N-channel MOSFET output that requires an external 2k pull-up resistor from 1.8V to 3.3V. If readback from the mode control registers is not needed, the pull-up resistor is not necessary and SDO can be left unconnected.

SDI (Pin 37): Serial Interface Data Input. In serial programming mode, (PAR/ \overline{SER} = 0V), SDI is the serial interface data input. Data on SDI is clocked into the mode control registers on the rising edge of SCK. In parallel programming mode (PAR/ \overline{SER} = V_{DD}), SDI selects 3.5mA or 1.75mA LVDS output current (see Table 2).

SCK (Pin 38): Serial Interface Clock Input. In serial programming mode, (PAR/ \overline{SER} = 0V), SCK is the serial interface clock input. In parallel programming mode (PAR/ \overline{SER} = V_{DD}), SCK controls the sleep mode (see Table 2).

 $\overline{\text{CS}}$ (Pin 39): Serial Interface Chip Select Input. In serial programming mode, (PAR/ $\overline{\text{SER}}$ = 0V), $\overline{\text{CS}}$ is the serial interface chip select input. When $\overline{\text{CS}}$ is low, SCK is enabled for shifting data on SDI into the mode control registers. In parallel programming mode (PAR/ $\overline{\text{SER}}$ = V_{DD}), $\overline{\text{CS}}$ controls the clock duty cycle stabilizer (see Table 2).

PAR/SER (**Pin 40**): Programming Mode Selection Pin. Connect to ground to enable the serial programming mode. \overline{CS} , SCK, SDI and SDO become a serial interface that control the A/D operating modes. Connect to V_{DD} to enable the parallel programming mode where \overline{CS} , SCK and SDI become parallel logic inputs that control a reduced set of the A/D operating modes. PAR/ \overline{SER} should be connected directly to ground or the V_{DD} of the part and not be driven by a logic signal.

PIN FUNCTIONS

LVDS Outputs (DDR LVDS)

The following pins are differential LVDS outputs. The output current level is programmable. There is an optional internal 100Ω termination resistor between the pins of each LVDS output pair.

 $D_{0_1}^-/D_{0_1}^+$ to $D_{12_13}^-/D_{12_13}^+$ (Pins 16/17, 18/19, 22/23, 24/25, 28/29, 31/32, 33/34): Double-Data Rate Digital Outputs. Two data bits are multiplexed onto each differential output pair. The even data bits (D0, D2, D4, D6, D8, D10, D12) appear when CLKOUT+ is low. The odd data bits (D1, D3, D5, D7, D9, D11, D13) appear when CLKOUT+ is high.

CLKOUT⁻/**CLKOUT**⁺ (**Pins 26/27**): Data Output Clock. The digital outputs normally transition at the same time as the falling and rising edges of CLKOUT⁺. The phase of CLKOUT⁺ can also be delayed relative to the digital outputs by programming the mode control registers.

OF⁺**(Pins 14/15):** Over/Underflow Digital Output. OF⁺ is high when an overflow or underflow has occurred. This underflow is valid only when CLKOUT⁺ is low. In the second half clock cycle, the overflow is set to 0.

FUNCTIONAL BLOCK DIAGRAM

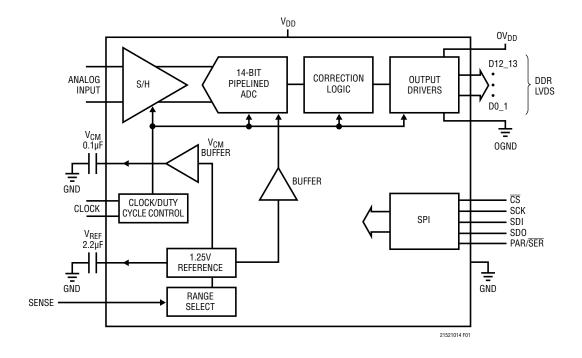
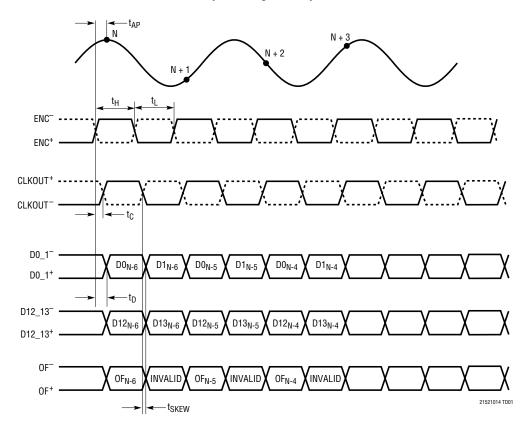


Figure 1. Functional Block Diagram

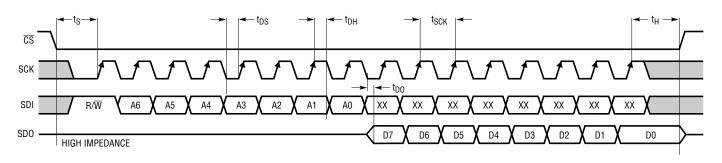


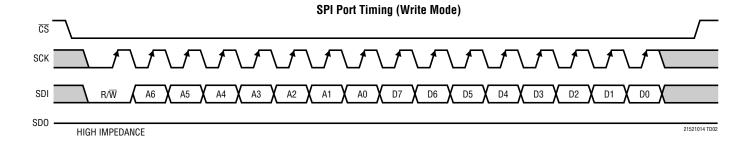
TIMING DIAGRAMS

Double-Data Rate Output Timing, All Outputs Are Differential LVDS



SPI Port Timing (Readback Mode)





CONVERTER OPERATION

The LTC2152-14/LTC2151-14/LTC2150-14 are 14-bit 250Msps/210Msps/170Msps A/D converters that are powered by a single 1.8V supply. The analog inputs must be driven differentially. The encode inputs should be driven differentially for optimal performance. The digital outputs are double-data rate LVDS. Additional features can be chosen by programming the mode control registers through a serial SPI port.

ANALOG INPUT

The analog input is a differential CMOS sample-and-hold circuit (Figure 2). It must be driven differentially around a common mode voltage set by the V_{CM} output pin, which is nominally 0.8V. The inputs should swing from $V_{CM}-0.375V$ to $V_{CM}+0.375V$. There should be a 180° phase difference between the inputs.

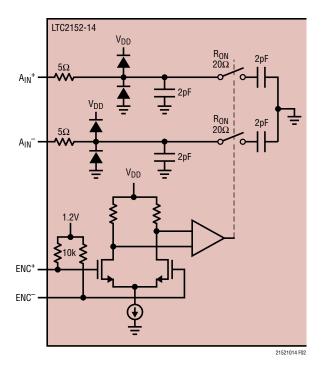


Figure 2. Equivalent Input Circuit for Differential Input Clock

INPUT DRIVE CIRCUITS

Input Filtering

If possible, there should be an RC lowpass filter right at the analog inputs. This lowpass filter isolates the drive circuitry from the A/D sample-and-hold switching, and also limits wide band noise from the drive circuitry. Figure 3 shows an example of an input RC filter. The RC component values should be chosen based on the application's input frequency.

Transformer-Coupled Circuits

Figure 3 shows the analog input being driven by an RF transformer with the common mode supplied through a pair of resistors via the V_{CM} pin.

At higher input frequencies a transmission line balun transformer (Figures 4 and 5) has better balance, resulting in lower A/D distortion.

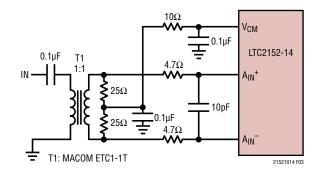


Figure 3. Analog Input Circuit Using a Transformer.

Recommended for Input Frequencies from 5MHz to 70MHz

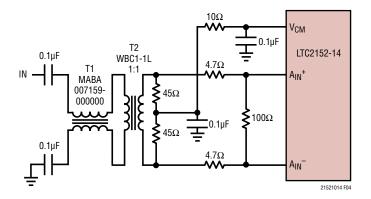


Figure 4. Recommended Front-End Circuit for Input Frequencies from 15MHz to 150MHz



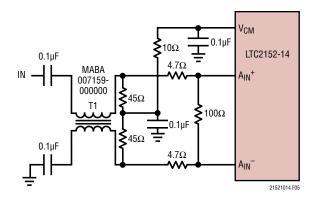


Figure 5. Recommended Front-End Circuit for Input Frequencies from 150MHz Up to 900MHz

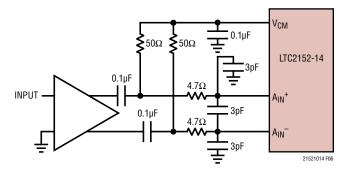


Figure 6. Front-End Circuit Using a High Speed Differential Amplifier

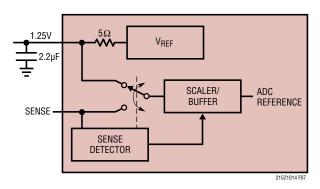


Figure 7. Reference Circuit

Amplifier Circuits

Figure 6 shows the analog input being driven by a high speed differential amplifier. The output of the amplifier is AC-coupled to the A/D so the amplifier's output common mode voltage can be optimally set to minimize distortion.

At very high frequencies an RF gain block will often have lower distortion than a differential amplifier. If the gain block is single-ended, then a transformer circuit (Figures 3 and 5) should convert the signal to differential before driving the A/D. The A/D cannot be driven single-ended.

Reference

The LTC2152-14/LTC2151-14/LTC2150-14 has an internal 1.25V voltage reference. For a 1.5V input range with internal reference, connect SENSE to V_{DD} . For a 1.5V input range with an external reference, apply a 1.25V reference voltage to SENSE (Figure 7).

Encode Input

The signal quality of the encode inputs strongly affects the A/D noise performance. The encode inputs should be treated as analog signals—do not route them next to digital traces on the circuit board.

The encode inputs are internally biased to 1.2V through 10k equivalent resistance (Figure 8). If the common mode of the driver is within 1.1V to 1.5V, it is possible to drive

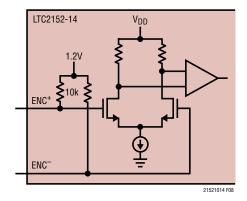


Figure 8. Equivalent Encode Input Circuit

the encode inputs directly. Otherwise, a transformer or coupling capacitors are needed (Figures 9 and 10). The maximum (peak) voltage of the input signal should never exceed V_{DD} +0.1V or go below -0.1V.

Clock Duty Cycle Stabilizer

For good performance the encode signal should have a 50% (±5%) duty cycle. If the optional clock duty cycle stabilizer circuit is enabled, the encode duty cycle can vary from 30% to 70% and the duty cycle stabilizer will maintain a constant 50% internal duty cycle. If the encode signal changes frequency or is turned off, the duty cycle stabilizer circuit requires one hundred clock cycles to lock onto the input clock. The duty cycle stabilizer is enabled via SPI Register A2 (see SPI Control Register) or by $\overline{\text{CS}}$ in parallel programming mode.

For applications where the sample rate needs to be changed quickly, the clock duty cycle stabilizer can be disabled. If the duty cycle stabilizer is disabled, care should be taken to make the sampling clock have a 50% (±5%) duty cycle.

DIGITAL OUTPUTS

The digital outputs are double-data rate LVDS signals. Two data bits are multiplexed and output on each differential output pair. There are seven LVDS output pairs (D0_1+/ D0_1⁻ through D12_13⁻/D12_13⁺). Overflow (OF⁺/OF⁻) and the data output clock (CLKOUT+/CLKOUT-) each have an LVDS output pair.

By default the outputs are standard LVDS levels: 3.5mA output current and a 1.25V output common mode voltage.

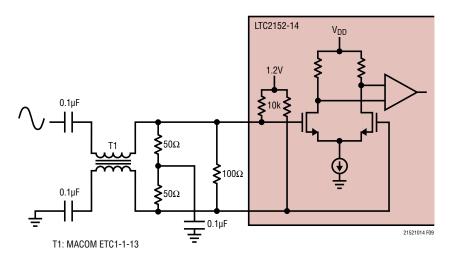


Figure 9. Sinusoidal Encode Drive

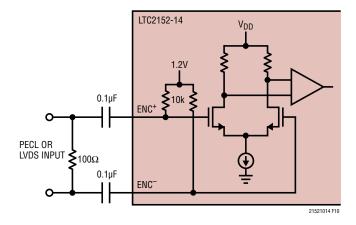


Figure 10. PECL or LVDS Encode Drive

An external 100Ω differential termination resistor is required for each LVDS output pair. The termination resistors should be located as close as possible to the LVDS receiver.

The outputs are powered by OV_{DD} and OGND, which are isolated from the A/D core power and ground.

Programmable LVDS Output Current

The default output driver current is 3.5mA. This current can be adjusted by serially programming mode control register A3 (see Table 3). Available current levels are 1.75mA, 2.1mA, 2.5mA, 3mA, 3.5mA, 4mA and 4.5mA.

Optional LVDS Driver Internal Termination

In most cases, using just an external 100Ω termination resistor will give excellent LVDS signal integrity. In addition, an optional internal 100Ω termination resistor can be enabled by serially programming mode control register A3. The internal termination helps absorb any reflections caused by imperfect termination at the receiver. When the internal termination is enabled, the output driver current is doubled to maintain the same output voltage swing.

Overflow Bit

The overflow output bit (OF) outputs a logic high when the analog input is either overranged or underranged. The overflow bit has the same pipeline latency as the data bits.

The OF is valid when CLKOUT+ is low.

Phase Shifting the Output Clock

To allow adequate set-up and hold time when latching the output data, the CLKOUT⁺ signal may need to be phase shifted relative to the data output bits. Most FPGAs have this feature; this is generally the best place to adjust the timing.

Alternatively, the ADC can also phase shift the CLKOUT⁺/ CLKOUT⁻ signals by serially programming mode control register A2. The output clock can be shifted by 0°, 45°, 90°, or 135°. To use the phase shifting feature, the clock duty cycle stabilizer must be turned on. Another control register bit can invert the polarity of CLKOUT⁺ and CLKOUT⁻, independently of the phase shift. The combination of these two features enables phase shifts of 45° up to 315° (Figure 11).

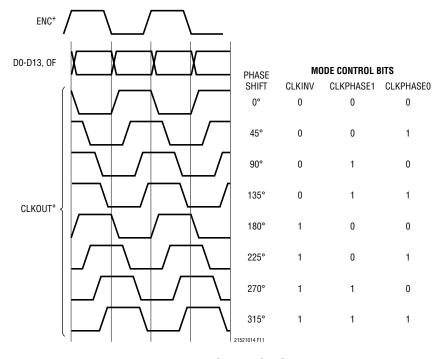


Figure 11. Phase Shifting CLKOUT



DATA FORMAT

Table 1 shows the relationship between the analog input voltage, the digital data output bits and the overflow bit. By default the output data format is offset binary. The 2's complement format can be selected by serially programming mode control register A4.

Table 1. Output Codes vs Input Voltage

A _{IN} ⁺ - A _{IN} ⁻ (1.5V Range)	0F	D13-D0 (Offset Binary)	D13-D0 (2's COMPLEMENT)
>0.75 V	1	11 1111 1111 1111	01 1111 1111 1111
+0.75V	0	11 1111 1111 1111	01 1111 1111 1111
+0.749908V	0	11 1111 1111 1110	01 1111 1111 1110
+0.0000915V	0	10 0000 0000 0001	00 0000 0000 0001
+0.000000V	0	10 0000 0000 0000	00 0000 0000 0000
-0.0000915V	0	01 1111 1111 1111	11 1111 1111 1111
-0.0001831V	0	01 1111 1111 1110	11 1111 1111 1110
-0.7499084V	0	00 0000 0000 0001	10 0000 0000 0001
-0.75V	0	00 0000 0000 0000	10 0000 0000 0000
< -0.75V	1	00 0000 0000 0000	10 0000 0000 0000

Digital Output Randomizer

Interference from the A/D digital outputs is sometimes unavoidable. Digital interference may be from capacitive or inductive coupling or coupling through the ground plane. Even a tiny coupling factor can cause unwanted tones in the ADC output spectrum. By randomizing the digital output before it is transmitted off-chip, these unwanted tones can be randomized, which reduces the unwanted tone amplitude.

The digital output is randomized by applying an exclusive-OR logic operation between the LSB and all other data output bits. To decode, the reverse operation is applied—an exclusive-OR operation is applied between the LSB and all other bits. The LSB, OF and CLKOUT outputs are not affected. The output randomizer is enabled by serially programming mode control register A4.

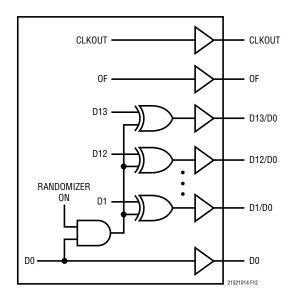


Figure 12. Functional Equivalent of Digital Output Randomizer

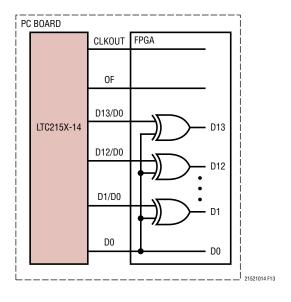


Figure 13. Unrandomizing for Randomized Digital Output Signal



Alternate Bit Polarity

Another feature that may reduce digital feedback on the circuit board is the alternate bit polarity mode. When this mode is enabled, all of the odd bits (D1, D3, D5, D7, D9, D11, D13) are inverted before the output buffers. The even bits (D0, D2, D4, D6, D8, D10, D12), OF and CLKOUT are not affected. This can reduce digital currents in the circuit board ground plane and reduce digital noise, particularly for very small analog input signals.

The digital output is decoded at the receiver by inverting the odd bits (D1, D3, D5, D7, D9, D11, D13.) The alternate bit polarity mode is independent of the digital output randomizer—either both or neither function can be on at the same time. The alternate bit polarity mode is enabled by serially programming mode control register A4.

Digital Output Test Patterns

To allow in-circuit testing of the digital interface to the A/D, there are several test modes (activate by setting DTESTON) that force the A/D data outputs (OF, D13 to D0) to known values:

All 1s: All outputs are 1 All 0s: All outputs are 0

Alternating: Outputs change from all 1s to all 0s on alternating samples

Checkerboard: Outputs change from 101010101010101 to 0101010101010 on alternating samples.

The digital output test patterns are enabled by serially programming mode control register A4. When enabled, the test patterns override all other formatting modes: 2's complement, randomizer, alternate-bit polarity.

Output Disable

The digital outputs may be disabled by serially programming mode control register A3. All digital outputs, including OF and CLKOUT, are disabled. The high impedance disabled state is intended for long periods of inactivity,

it is not designed for multiplexing the data bus between multiple converters.

Sleep Modes

The A/D may be placed in a power-down mode to conserve power. In sleep mode, the entire A/D converter is powered down, resulting in < 2mW power consumption. If the encode input signal is not disabled, the power consumption will be higher (up to 2mW at 250Msps). Sleep mode is enabled by mode control register A1 (serial programming mode), or by SCK (parallel programming mode).

The amount of time required to recover from sleep mode depends on the size of the bypass capacitors on V_{REF} . For the suggested values in Figure 1, the A/D will stabilize after 0.1ms + 2500 • t_p where t_p is the period of the sampling clock.

Nap Mode

In nap mode the A/D core is powered down while the internal reference circuits stay active, allowing faster wakeup. Recovering from nap mode requires at least 100 clock cycles. Wake-up time from nap mode is guaranteed only if the clock is kept running, otherwise power-down wake-up time conditions apply. Nap mode is enabled by power-down register A1 in the serial programming mode.

DEVICE PROGRAMMING MODES

The operating modes of the LTC215X-14 can be programmed by either a parallel interface or a simple serial interface. The serial interface has more flexibility and can program all available modes. The parallel interface is more limited and can only program some of the more commonly used modes.

Parallel Programming Mode

To use the parallel programming mode, PAR/ \overline{SER} should be tied to V_{DD} . The \overline{CS} , SCK and SDI pins are binary logic inputs that set certain operating modes. These pins can be tied to V_{DD} or ground, or driven by 1.8V, 2.5V, or 3.3V



CMOS logic. Table 2 shows the modes set by $\overline{\text{CS}}$, SCK and SDI.

Table 2. Parallel Programming Mode Control Bits)

PIN	DESCRIPTION
CS	Clock Duty Cycle Stabilizer Control Bit
	0 = Clock Duty Cycle Stabilizer Off
	1 = Clock Duty Cycle Stabilizer On
SCK	Power-Down Control Bit
	0 = Normal Operation
	1 = Sleep Mode (entire ADC is powered down)
SDI	LVDS Current Selection Bit
	0 = 3.5mA LVDS Current Mode
	1 = 1.75mA LVDS Current Mode

Serial Programming Mode

To use the serial programming mode, PAR/SER should be tied to ground. The \overline{CS} , SCK, SDI and SDO pins become a serial interface that program the A/D control registers. Data is written to a register with a 16-bit serial word. Data can also be read back from a register to verify its contents.

Serial data transfer starts when \overline{CS} is taken low. The data on the SDI pin is latched at the first sixteen rising edges of SCK. Any SCK rising edges after the first sixteen are ignored. The data transfer ends when \overline{CS} is taken high again.

The first bit of the 16-bit input word is the R/\overline{W} bit. The next seven bits are the address of the register (A6:A0). The final eight bits are the register data (D7:D0).

If the R/\overline{W} bit is low, the serial data (D7:D0) will be written to the register set by the address bits (A6:A0). If the R/\overline{W} bit is high, data in the register set by the address bits (A6:A0) will be read back on the SD0 pin (see the Timing Diagrams). During a readback command the register is not updated and data on SDI is ignored.

The SDO pin is an open-drain output that pulls to ground with a 200Ω impedance. If register data is read back through SDO, an external 2k pull-up resistor is required. If serial data is only written and readback is not needed, then SDO can be left floating and no pull-up resistor is needed. Table 3 shows a map of the mode control registers.

Software Reset

If serial programming is used, the mode control registers should be programmed as soon as possible after the power supplies turn on and are stable. The first serial command must be a software reset which will reset all register data bits to logic 0. To perform a software reset it is necessary to write 1 in register A0 (Bit D7). After the reset is complete, Bit D7 is automatically set back to zero. This register is WRITE-ONLY.

GROUNDING AND BYPASSING

The LTC215X-14 requires a printed circuit board with a clean unbroken ground plane in the first layer beneath the ADC. A multilayer board with an internal ground plane is recommended. Layout for the printed circuit board should ensure that digital and analog signal lines are separated as much as possible. In particular, care should be taken not to run any digital track alongside an analog signal track or underneath the ADC.

High quality ceramic bypass capacitors should be used at the V_{DD} , OV_{DD} , V_{CM} and V_{REF} pins. Bypass capacitors must be located as close to the pins as possible. Size 0402 ceramic capacitors are recommended. The traces connecting the pins and bypass capacitors must be kept short and should be made as wide as possible.

The analog inputs, encode signals and digital outputs should not be routed next to each other. Ground fill and grounded vias should be used as barriers to isolate these signals from each other.

HEAT TRANSFER

Most of the heat generated by the LTC215X-14 is transferred from the die through the bottom-side exposed pad and package leads onto the printed circuit board. For good electrical and thermal performance, the exposed pad must be soldered to a large grounded pad on the PC board. This pad should be connected to the internal ground planes by an array of vias.

LINEAR TECHNOLOGY

Table 3. Serial Programming Mode Register Map (PAR/SER = GND). An "X" indicates an unused bit.

REGISTER AO: RESET REGISTER (ADDRESS 00h) WRITE-ONLY

D7	D6	D5	D4	D3	D2	D1	D0
RESET	X	Χ	Χ	Х	Χ	Χ	Х

Bit 7 **RESET** Software Reset Bit

0 = Not Used

1 = Software Reset. All mode control registers are reset to 00h. After the Reset SPI Write Command is Complete, Bit D7 is

Automatically Set Back to Zero. The Reset Register is Write Only.

Bits 6-0 Unused bit.

REGISTER A1: POWER-DOWN REGISTER (ADDRESS 01h)

D7	D6	D5	D4	D3	D2	D1	D0
Χ	Χ	Χ	Χ	SLEEP	NAP	0	0

Bits 7-4 Unused, these bits are read back as 0.

Bit 3 SLEEP

0 = Normal Operation

1 = Power Down Entire ADC

Bit 2 NAF

0 = Normal Mode

1 = Low Power Mode

Bit 1-0 Must be set to 0.

REGISTER A2: TIMING REGISTER (ADDRESS 02h)

D7	D6	D5	D4	D3	D2	D1	D0
Χ	Х	Х	Х	CLKINV	CLKPHASE1	CLKPHASE0	DCS

Bits 7-4 Unused, these bits are read back as 0.

Bit 3 CLKINV Output Clock Invert Bit

0 = Normal CLKOUT Polarity (as shown in the Timing Diagrams)

1 = Inverted CLKOUT Polarity

Bits 2-1 **CLKPHASE1:CLKPHASE0** Output Clock Phase Delay Bits

00 = No CLKOUT Delay (as shown in the Timing Diagrams) 01 = CLKOUT+/CLKOUT- delayed by 45° (Clock Period • 1/8) 10 = CLKOUT+/CLKOUT- delayed by 90° (Clock Period • 1/4) 11 = CLKOUT+/CLKOUT- delayed by 135° (Clock Period • 3/8)

Note: If the CLKOUT phase delay feature is used, the clock duty cycle stabilizer must also be turned on.

Bit 0 DCS Clock Duty Cycle Stabilizer Bit

0 = Clock Duty Cycle Stabilizer Off 1 = Clock Duty Cycle Stabilizer On



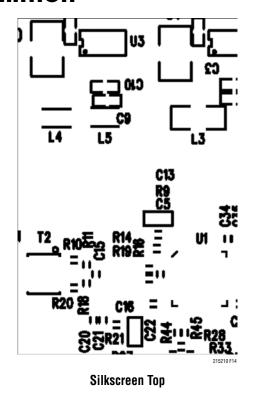
REGISTER A3: OUTPUT MODE REGISTER (ADDRESS 03h)

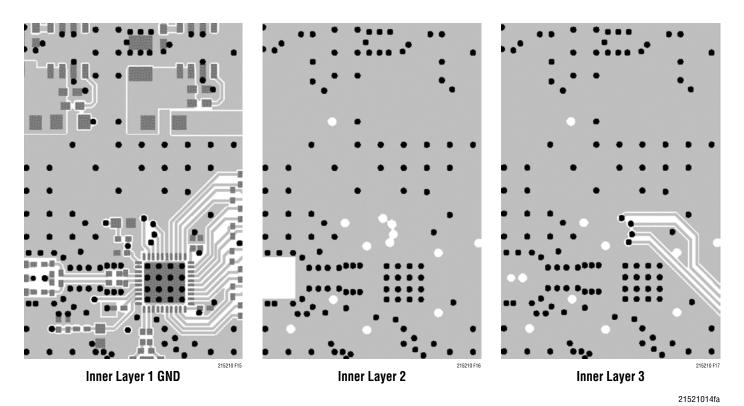
D7	D6	D5	D4	D3	D2	D1	D0
Х	Х	Х	ILVDS2	ILVDS1	ILVDS0	TERMON	OUT0FF
Bits 7-5	Unused, these bits	are read back as 0					
Bits 4-2	ILVDS2:ILVDS0 LVDS Output Current Bits 000 = 3.5mA LVDS Output Driver Current 001 = 4.0mA LVDS Output Driver Current 010 = 4.5mA LVDS Output Driver Current 011 = Not Used 100 = 3.0mA LVDS Output Driver Current 101 = 2.5mA LVDS Output Driver Current 110 = 2.1mA LVDS Output Driver Current 111 = 1.75mA LVDS Output Driver Current						
Bit 1	0 = Internal Termir			s 2× the current set	by ILVDS2:ILVDS0		
Bit 0	OUTOFF Die 0 = LVDS DDR	gital Output Mode C	Control Bits				

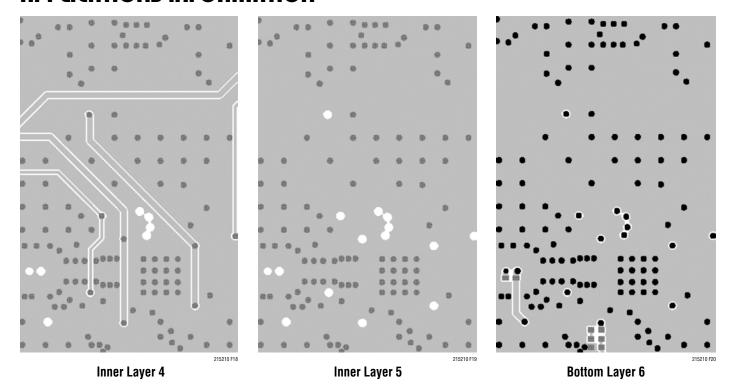
REGISTER A4: DATA FORMAT REGISTER (ADDRESS 04h)

1 = LVDS Tristate (High Impedance)

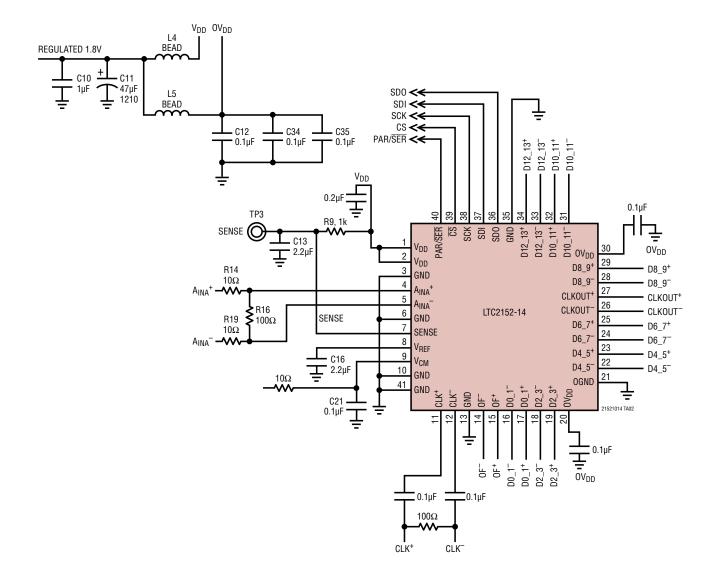
D7	D6	D5	D4	D3	D2	D1	D0	
OUTTEST2	OUTTEST1	OUTTEST0	ABP	0	DTESTON	RAND	TWOSCOMP	
Bits 7-5	OUTTEST2:OUTTEST0 Digital Output Test Pattern Bits 000 = All Digital Outputs = 0 001 = All Digital Outputs = 1 010 = Alternating Output Pattern. OF, D13-D0 alternate between 000 0000 0000 and 111 1111 1111 1111 100 = Checkerboard Output Pattern. OF, D13-D0 alternate between 010 1010 1010 1010 and 101 0101 0101							
Bit 4	ABP Alternate Bit Polymer 1 = Alternate Bit Polymer 1	,	Mode Control Bit					
Bit 3	Must be set to 0.							
Bit 2	DTESTON 0 = Normal Mode 1 = Enable the Dig	Enable digital pa ital Output Test Patt	,					
Bit 1	0 = Data Output Ra	ta Output Randomiz andomizer Mode Of andomizer Mode On	f	t				
Bit 0	TWOSCOMP Two 0 = Offset Binary D 1 = Two's Compler		de Control Bit					







TYPICAL APPLICATIONS

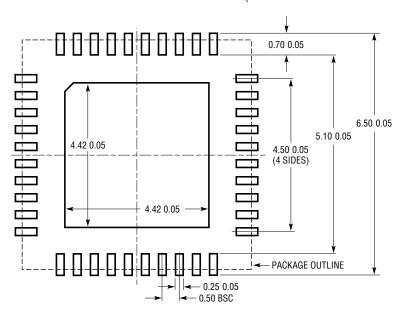


PACKAGE DESCRIPTION

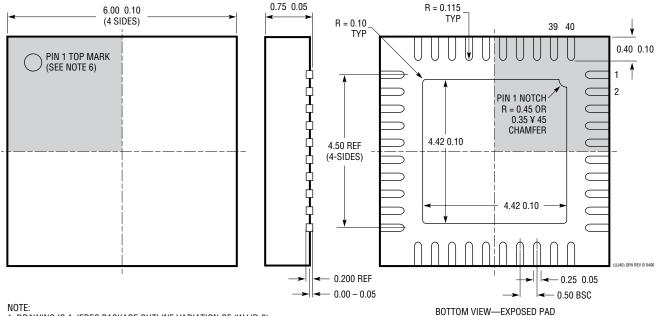
Please refer to http://www.linear.com/designtools/packaging/ for the most recent package drawings.

UJ Package 40-Lead Plastic QFN (6mm × 6mm)

(Reference LTC DWG # 05-08-1728 Rev Ø)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS APPLY SOLDER MASK TO AREAS THAT ARE NOT SOLDERED



- 1. DRAWING IS A JEDEC PACKAGE OUTLINE VARIATION OF (WJJD-2)
 2. DRAWING NOT TO SCALE

- 3. ALL DIMENSIONS ARE IN MILLIMETERS
 4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE
 - MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.20mm ON ANY SIDE, IF PRESENT
- 5. EXPOSED PAD SHALL BE SOLDER PLATED
- 6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

REVISION HISTORY

REV	DATE	DESCRIPTION	
Α	12/14	Changed pipeline latency to 6	5 and 17
		Updated G17	8

